

SINGLE INVERTER GATE

Description

The Advanced Ultra Low Power (AUP) CMOS logic family is designed for low power and extended battery life in portable applications.

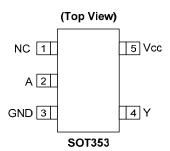
The 74AUP1G04 is a single inverter gate with a standard push-pull output designed for operation over a power supply range of 0.8V to 3.6V. The device is fully specified for partial power down applications using $I_{\rm OFF}$. The $I_{\rm OFF}$ circuitry disables the output preventing damaging current backflow when the device is powered down. The gate performs the positive Boolean function:

$$\mathsf{Y}=\overline{\mathsf{A}}$$

Features

- Advanced Ultra Low Power (AUP) CMOS
- Supply Voltage Range from 0.8V to 3.6V
- ± 4 mA Output Drive at 3.0V
- Low Static power consumption
 - I_{CC} < 0.9µA
- Low Dynamic Power Consumption
 - C_{PD} = 6.1pF (Typical at 3.6V)
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time. The hysteresis is typically 250mV at $\,$ V_{CC} = 3.0V
- I_{OFF} Supports Partial-Power-Down Mode Operation
- ESD Protection Exceeds JESD 22
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options SOT353, DFN1410, and DFN1010
- Leadless packages per JESD30E
 - DFN1010 denoted as X2-DFN1010-6
 - DFN1014 denoted as X2-DFN1014-6
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



(Top View)

NC	<u> </u>	[6	Vcc
Α	2]	5	NC
GND	3]	. 4	Υ

DFN1410

(Top View)

NC	1	6	Vcc
Α	2]	5	NC
GND			Υ

DFN1010

Applications

- Suited for battery and low power needs
- Wide array of products such as:
 - Tablets, E-readers
 - Cell Phones, Personal Navigation / GPS
 - MP3 players ,Cameras, Video Recorders
 - PCs ultrabooks, notebooks, netbooks,
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

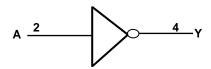
Click here for ordering information, located at the end of datasheet



Pin Descriptions

Pin Name	Function
NC	No Connection
Α	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Inputs	Output
Α	Υ
Н	L
L	Н



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
V _{CC}	Supply Voltage Range	-0.5 to +4.6	V
VI	Input Voltage Range	-0.5 to +4.6	V
Vo	Voltage applied to output in high or low state	-0.5 to V _{CC} +0.5	V
lık	Input Clamp Current V _I <0	50	mA
lok	Output Clamp Current (V _O < 0)	50	mA
Io	Continuous Output Current (V _O = 0 to V _{CC})	±20	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Note:

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Para	nmeter	Min	Max	Unit
Vcc	Operating Voltage		0.8	3.6	V
VI	Input Voltage		0	3.6	V
Vo	Output Voltage		0	Vcc	V
		$V_{CC} = 0.8 V$		-20	μA
		V _{CC} = 1.1 V		-1.1	
	Lligh lovel output ourrent	V _{CC} = 1.4 V		-1.7	
I _{OH}	High-level output current	V _{CC} = 1.65 V		-1.9	mA
		$V_{CC} = 2.3 \text{ V}$		-3.1	
		V _{CC} = 3.0 V		-4	
		V _{CC} = 0.8 V		20	uA
	OL Low-level output current	V _{CC} = 1.1 V		1.1	
		V _{CC} = 1.4 V		1.7	
IOL	Low-lever output current	V _{CC} = 1.65 V		1.9	mA
		V _{CC} = 2.3 V		3.1	
		V _{CC} = 3.0 V		4	
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 0.8 V to 3.6 V		200	ns/V
T _A	Operating free-air temperature		-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Electrical Characteristics

Complete	Donomatan	Took Conditions	.,	T _A = -	+25°C	T _A = -40°C	C to +85°C	Uni
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Uni
			0.8V to 1.65V	0.80 X V _{CC}		0.80 X V _{CC}		
	High-Level Input		1.65V to 1.95V	0.65 X V _{CC}		0.65 X V _{CC}		
V_{IH}	Voltage		2.3V to 2.7V	1.6		1.6		V
			3.0V to 3.6V	2.0		2.0		
			0.8V to 1.65V		0.30 X V _{CC}		0.30 X V _{CC}	
	Low-Level Input		1.65V to 1.95V		0.35 X V _{CC}		0.35 X V _{CC}	V
V_{IL}	Voltage		2.3V to 2.7V		0.7		0.7	V
			3.0V to 3.6V		0.9		0.9	
		$I_{OH} = -20 \mu A$	0.8V to 3.6V	V _{CC} - 0.1		V _{CC} – 0.1		
		I _{OH} = -1.1mA	1.1V	0.75 X V _{CC}		0.7 X V _{CC}		
		I _{OH} = -1.7mA	1.4V	1.11		1.03		V
	High-Level Output	I _{OH} = -1.9mA	1.65V	1.32		1.3		
V_{OH}	Voltage	I _{OH} = -2.3mA	0.017	2.05		1.97		
		I _{OH} = -3.1mA	2.3V	1.9		1.85		
		I _{OH} = -2.7mA		2.72		2.67		
		I _{OH} = -4mA	3V	2.6		2.55		
		I _{OL} = 20μA	0.8V to 3.6V		0.1		0.1	
		I _{OL} = 1.1mA	1.1V		0.3 X V _{CC}		0.3 X V _{CC}	
		I _{OL} = 1.7mA	1.4V		0.31		0.37	
	High-Level Input	I _{OL} = 1.9mA	1.65V		0.31		0.35	
V_{OL}	Voltage	I _{OL} = 2.3mA	1		0.31		0.33	٧
		I _{OL} = 3.1mA	2.3V		0.44		0.45	
		$I_{OL} = 2.7 \text{mA}$			0.31		0.33	
		$I_{OL} = 4mA$	3V		0.44		0.45	
II	Input Current	A or B Input V _I = GND to 3.6V	0V to 3.6V		± 0.1		± 0.5	μ
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0		0.2		0.6	μ
Δl _{OFF}	Delta Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0V to 0.2V		0.2		0.6	μ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	0.8V to 3.6V		0.5		0.9	μA
ΔI _{CC}	Additional Supply Current	Input at V _{CC} -0.6	3.3V		40		50	μΑ



Electrical Characteristics (cont.)

Comple ed	Danamatan	Took Conditions	.,	T _A = -40°C	to +125°C	l lmit
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Unit
			0.8V to 1.65V	0.80 X V _{CC}		
V	High-level Input		1.65V to 1.95V	0.70 X V _{CC}		
V_{IH}	Voltage		2.3V to 2.7V	1.6		v
			3.0V to 3.6V	2.0		
			0.8V to 1.65V		0.25 X V _{CC}	
V_{IL}	Low-level input		1.65V to 1.95V		0.30 X V _{CC}	V
VIL	voltage		2.3V to 2.7V		0.7	
			3.0V to 3.6V		0.9	
		I _{OH} = -20μA	0.8V to 3.6V	V _{CC} – 0.11		
		I _{OH} = -1.1mA	1.1V	0.6 X V _{CC}		
		$I_{OH} = -1.7 \text{mA}$	1.4V	0.93		
.,	High Level Output	$I_{OH} = -1.9 \text{mA}$	1.65V	1.17		V
Vон	Voltage	I _{OH} = -2.3mA	2.3V	1.77		V
		I _{OH} = -3.1mA	2.3	1.67		
		I _{OH} = -2.7mA	2)./	2.40		
		I _{OH} = -4mA	3V	2.30		
		I _{OL} = 20μA	0.8V to 3.6V		0.11	
		I _{OL} = 1.1mA	1.1V		0.33 X V _{CC}	
		I _{OL} = 1.7mA	1.4V		0.41	
	High-level Input	I _{OL} = 1.9mA	1.65V		0.39	
V_{OL}	Voltage	I _{OL} = 2.3mA			0.36	V
		I _{OL} = 3.1mA	2.3V		0.50	
		I _{OL} = 2.7mA			0.36	
		I _{OL} = 4mA	3V		0.50	
II	Input Current	A or B Input V _I = GND to 3.6V	0V to 3.6V		± 0.75	μА
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0V		± 3.5	μА
ΔI_{OFF}	Delta Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0V to 0.2V		± 2.5	μА
I _{CC}	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	0.8V to 3.6V		3.0	μA
ΔI _{CC}	Additional Supply Current	Input at V _{CC} -0.6V Other inputs at V _{CC} or GND	3.3V		75	μA



Switching Characteristics

 $C_L = 5pF$ see Figure 1

Parameter	From Input	TO OUTPUT	V	T _A = +25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		T _A = -40°C to +125°C		Unit
i arameter			Vcc	Min	Тур	Max	Min	Max	Min	Max	Onit
			V8.0		16.0						
			1.2V ± 0.1V	2.4	5.0	10.3	2.1	14.1	2.1	14.1	
	۸ or D	V	1.5V ± 0.1V	1.8	3.6	6.4	1.6	7.4	1.6	8.2	
t _{pd} A or B	Ť	1.8V ± 0.15V	1.5	2.9	5.0	1.4	5.9	1.4	6.5	ns	
			$2.5V \pm 0.2V$	1.2	2.4	3.9	1.1	4.5	1.1	5.0	
			$3.3V \pm 0.3V$	1.1	2.1	3.2	1.1	3.9	1.1	4.3	

 $C_L = 10pF$ see Figure 1

Parameter	From	TO	V	T,	_A = +25°C	;	$T_A = -40$ °C to +85°C		T _A = -40°C	to +125°C	Unit
Inpu	Input	OUTPUT	Vcc	Min	Тур	Max	Min	Max	Min	Max	Ollit
			V8.0		19.8						
			1.2V ± 0.1V	2.8	5.9	12.2	2.6	17.0	2.6	17.0	ns
	A or B	rB Y	1.5V ± 0.1V	2.3	4.2	7.5	2.1	8.7	2.1	9.6	
t _{pd} A or B	AUID		1.8V ± 0.15V	2.0	3.5	5.9	1.8	7.0	1.8	7.7	
			2.5V ± 0.2V	1.7	2.9	4.6	1.5	5.4	1.5	6.0	
			$3.3V \pm 0.3V$	1.4	2.7	3.8	1.4	4.5	1.4	5.0	

C_L = 15pF see Figure 1

Parameter	From	то	.,	T,	$T_A = +25^{\circ}C$			to +85°C	$T_A = -40$ °C	to +125°C	Unit
Input	OUTPUT	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Onit	
		V8.0		23.3							
		1.2V ± 0.1V	3.2	8.0	14.0	3.0	26.0	3.0	26.0		
	Λ o π D	V	1.5V ± 0.1V	2.6	7.5	9.0	2.4	10.0	2.4	11.0]
τ_{pd}	t _{pd} A or B Y	Ť	1.8V ± 0.15V	2.3	5.2	6.7	2.1	8.0	2.1	8.8	ns
		2.5V ± 0.2V	2.1	3.1	5.1	1.8	6.1	1.8	6.8	7	
		3.3V ± 0.3V	1.8	3.1	4.2	1.8	5.0	1.8	5.5		

 $C_L = 30pF$ see Figure 1

Parameter	From Input	TO OUTPUT	V	T _A = +25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		T _A = -40°C	Unit	
i ai ailletei			V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Offic
			V8.0		33.6						
			1.2V ± 0.1V	4.4	13.0	18.0	4.0	27.0	4.0	27.0	- ns
	A or D	V	1.5V ± 0.1V	3.6	6.3	12.0	3.2	13.8	3.2	14.2	
t _{pd} A or B	AUID	ı	1.8V ± 0.15V	3.2	5.3	9.0	2.9	10.5	2.9	11.6	
			$2.5V \pm 0.2V$	2.9	4.5	6.5	2.6	7.6	2.6	8.4	
			$3.3V \pm 0.3V$	2.1	4.2	5.4	2.1	6.2	2.1	6.9	

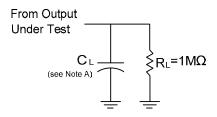


Operating and Package Characteristics (@T_A = +25°C, unless otherwise specified.)

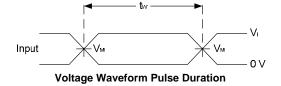
	Parameter	Test Co	nditions	Vcc	Тур	Unit	
				0.8V	6.5		
				1.2V ± 0.1V	6.3		
0	Power Dissipation	f = 1MHz		1.5V ± 0.1V	6.3		
C_{pd}	Capacitance			1.8V ± 0.15V	6.2	pF	
			2.5V ± 0.2V	6.2			
				3.3V ± 0.3V	6.1		
Ci	Input Capacitance	$V_i = V_{CC}$ or GND		0V or 3.3V	1.5	pF	
	θ _{JA} Thermal Resistance Junction-to-Ambient SOT353 X2-DFN1410-6 X2-DFN1010-6 (Note 6)		SOT353			371	
A.A.		X2-DFN1410-6	(Note 6)		430	°C/W	
				445			
	Thermal Resistance	SOT353			143		
θ_{JC}		Thermal Resistance Junction-to-Case X2-DFN1410-6 (Note 6		190	°C/W		
Juncti	Julicuon-lo-Case	X2-DFN1010-6			250		

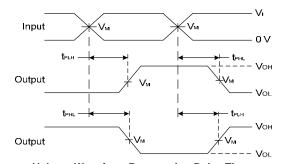
Note:

Parameter Measurement Information



V	Inp	outs	V _M	C _L
V _{cc}	VI	t _r /t _f		
0.8V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.2V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.5V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.8V±0.15V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
2.5V±0.2V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
3.3V±0.3V	Vcc	≤3ns	V _{CC} /2	5, 10, 15, 30pF





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

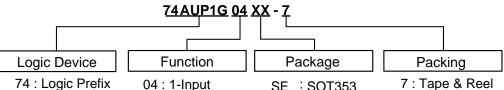
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

^{6.} Test condition for SOT353, DFN1410, and DFN1010 devices mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad lavout.



Ordering Information



AUP: 0.8 V to 3.6 V

Logic Family 1G : One gate

Inverter -Gate

SE: SOT353

7: Tape & Reel

FZ4: X2-DFN1410-6 FW4: X2-DFN1010-6

10	• '	guic

	Part Number	Baakaga Cada	Packaging	7" Tape and Reel	
	rait Nullibei	Package Code	rackaging	Quantity	Part Number Suffix
P	74AUP1G04SE-7	SE	SOT353	3000/Tape & Reel	-7
Pb,	74AUP1G04FZ4-7	FZ4	X2-DFN1410-6	5000/Tape & Reel	-7
Pb.	74AUP1G04FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7

Marking Information

(1) SOT353

(Top View)

XX Y WX2 3

XX: Identification code

Y: Year 0~9

 \underline{W} : Week : A $^{\sim}$ Z : 1 $^{\sim}$ 26 week; a~z: 27~52 week; z represents

52 and 53 week \underline{X} : $A^{\sim}Z$: Internal code

Part Number	Package	Identification Code
74AUP1G04SE	SOT353	XK

(2) X2-DFN1410-6 and X2-DFN1010-6

(Top View)

<u>XX</u> $\underline{Y}\underline{W}\underline{X}$ XX: Identification Code

Y: Year: 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

52 and 53 week X: A~Z: Internal code

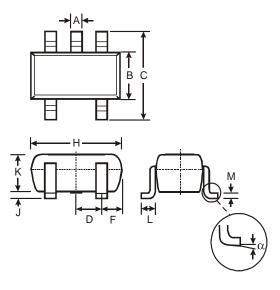
Part Number	Package	Identification Code
74AUP1G04FZ4	X2-DFN1410-6	XK
74AUP1G04FW4	X2-DFN1010-6	XK



Package Outline Dimensions (All dimensions in mm.)

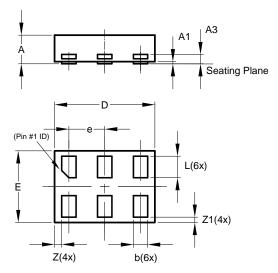
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(1) SOT353



	SOT353				
Dim	Min	Max	Тур		
Α	0.10	0.30	0.25		
В	1.15	1.35	1.30		
C	2.00	2.20	2.10		
D	0	.65 Typ)		
F	0.40	0.45	0.425		
Н	1.80	2.20	2.15		
7	0	0.10	0.05		
K	0.90	1.00	1.00		
L	0.25	0.40	0.30		
M	0.10	0.22	0.11		
α	0°	8°	-		
All Dimensions in mm					

(2) X2-DFN1410-6



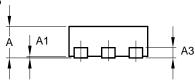
	X2-DFN1410-6				
Dim	Min	Max	Тур		
Α	_	0.40	0.39		
A1	0.00	0.05	0.02		
A3		_	0.13		
b	0.15	0.25	0.20		
D	1.35	1.45	1.40		
Е	0.95	1.05	1.00		
е	_		0.50		
L	0.25	0.35	0.30		
Z	_	_	0.10		
Z 1	0.045	0.105	0.075		
All Dimensions in mm					

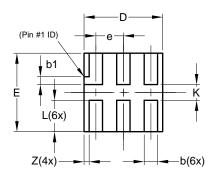


Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(3) X2-DFN1010-6



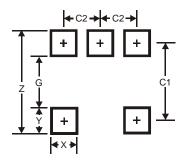


	X2-DFN1010-6				
Dim	Min	Max	Тур		
Α		0.40	0.39		
A1	0.00	0.05	0.02		
A3			0.13		
b	0.14	0.20	0.17		
b1	0.05	0.15	0.10		
D	0.95	1.05	1.00		
Е	0.95	1.05	1.00		
е			0.35		
Ĺ	0.35	0.45	0.40		
K	0.15				
Z			0.065		
All I	All Dimensions in mm				

Suggested Pad Layout

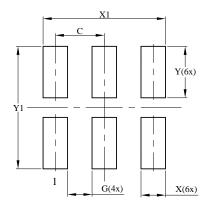
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version

(1) SOT353



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65

(2) X2-DFN1410-6



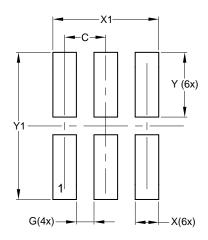
Dimensions	Value (in mm)
С	0.500
G	0.250
X	0.250
X1	1.250
Υ	0.525
Y1	1.250



Suggested Pad Layout (cont.)

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(3) X2-DFN1010-6



Dimensions	Value (in mm)
С	0.350
G	0.150
Х	0.200
X1	0.900
Y	0.550
Y1	1.250

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